# BAR42FILM BAR43FILM

## SMALL SIGNAL SCHOTTKY DIODE

**Table 1: Main Product Characteristics** 

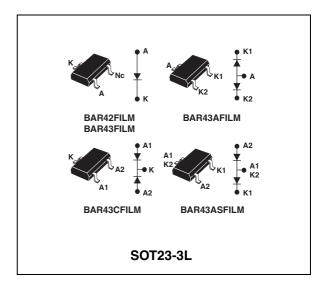
I <sub>F(AV)</sub>	0.1 A
V <sub>RRM</sub>	30 V
T <sub>j</sub>	150°C
V <sub>F</sub> (max)	0.33 and 0.40 V

#### **FEATURES AND BENEFITS**

- Very small conduction losses
- Negligible switching losses
- Low forward voltage drop
- Surface mount device

### **DESCRIPTION**

Genral purpose metal to silicon diodes featuring very low turn-on voltage and fast switching.



**Table 2: Order Codes** 

Part Number	Marking
BAR42FILM	D94
BAR43FILM	D95
BAR43AFILM	DB1
BAR43CFILM	DB2
BAR43SFILM	DA5

Table 3: Absolute Ratings (limiting values)

Symbol	Parameter	Value	Unit	
$V_{RRM}$	Repetitive peak reverse voltage	30	V	
I <sub>F(AV)</sub>	Continuous forward current		0.1	Α
I <sub>FSM</sub>	Surge non repetitive forward current	0.75	Α	
P <sub>tot</sub>	Power dissipation (note 1)	250	mW	
T <sub>stg</sub>	Maximum storage temperature range	-65 to + 150	°C	
Tj	Maximum operating junction temperature *	150	°C	
T <sub>L</sub>	Maximum temperature for soldering during 10	260	°C	

Note 1: for double diodes,  $P_{\mbox{tot}}$  is the total dissipation of both diodes.

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<sup>\*:</sup>  $\frac{dPtot}{dTj} > \frac{1}{Rth(j-a)}$  thermal runaway condition for a diode on its own heatsink

**Table 4: Thermal Resistance** 

Symbol	Parameter	Value	Unit
R <sub>th(j-a)</sub>	Junction to ambient (*)	500	°C/W

<sup>(\*)</sup> Mounted on epoxy board with recommended pad layout.

**Table 5: Static Electrical Characteristics** 

Symbol	Parameter	Tests conditions			Min.	Тур	Max.	Unit
V <sub>BR</sub>	Breakdown voltage	T <sub>j</sub> = 25°C		$I_R = 100 \mu A$	30			V
I <sub>R</sub> *	Poverce leakage current	verse leakage current $\frac{T_j = 25^{\circ}C}{T_j = 100^{\circ}C}$		V V			500	nA
'R	neverse leakage current			$V_R = V_{RRM}$			100	μΑ
			BAR42	$I_F = 10mA$		0.35	0.40	
	V <sub>F</sub> ** Forward voltage drop	T <sub>j</sub> = 25°C		I <sub>F</sub> = 50mA		0.50	0.65	
V <sub>F</sub> **			BAR43	$I_F = 2mA$	0.26		0.33	V
			DAN43	I <sub>F</sub> = 15mA			0.45	
			ALL	I <sub>F</sub> = 100mA			1	

Pulse test:

**Table 6: Dynamic Characteristics**  $(T_i = 25^{\circ}C)$ 

Symbol	Parameter	Tests conditions	Min.	Тур.	Max.	Unit
С	Junction capacitance	$T_j = 25^{\circ}C$ $V_R = 1V$ $F = 1$ MHz		7		pF
t <sub>rr</sub>	Reverse recovery time	$I_F = 10 \text{ mA}$ $I_R = 10 \text{ mA}$ $T_j = 25^{\circ}\text{C}$ $I_{rr} = 1 \text{ mA}$ $R_L = 100 \Omega$			5	ns
η	I I I I I I I I I I I I I I I I I I I	$C_L = 300 \text{ pF}  F = 45 \text{ MHz}$ $T_j = 25^{\circ}C  V_i = 2 \text{ V}  R_L = 50 \Omega$	80			%

Figure 1: Forward voltage drop versus forward current (typical values, low level)

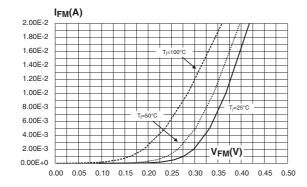
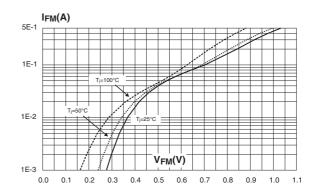


Figure 2: Forward voltage drop versus forward current (typical values, high level)



<sup>\*</sup> tp = 5 ms,  $\delta$  < 2%

<sup>\*\*</sup> tp = 380 µs,  $\delta$  < 2%

Figure 3: Reverse leakage current versus reverse voltage applied (typical values)

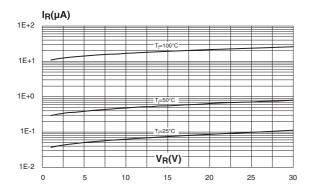


Figure 5: Junction capacitance versus reverse voltage applied (typical values)

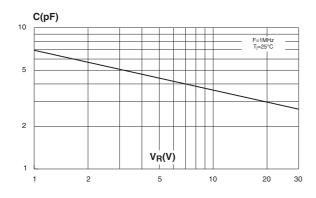


Figure 7: Thermal resistance junction to ambient versus copper surface under each lead (Epoxy printed circuit board FR4, copper thickness: 35µm)

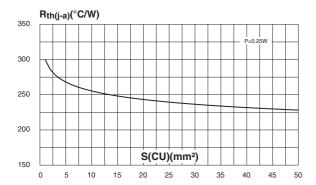


Figure 4: Reverse leakage current versus junction temperature

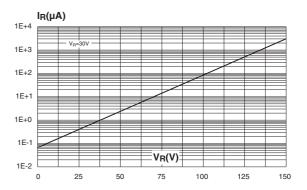
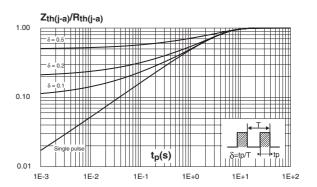
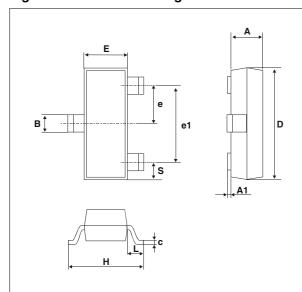


Figure 6: Relative variation of thermal impedance junction to ambient versus pulse duration (epoxy FR4 with recommended pad layout,  $e(Cu)=35\mu m$ )



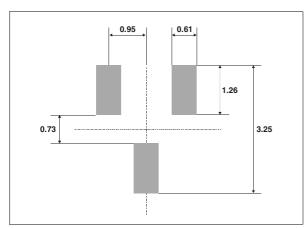
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Figure 8: SOT23-3L Package Mechanical Data



	DIMENSIONS			
REF.	Millim	neters	Inc	hes
	Min.	Max.	Min.	Max.
Α	0.89	1.4	0.035	0.055
A1	0	0.1	0	0.004
В	0.3	0.51	0.012	0.02
С	0.085	0.18	0.003	0.007
D	2.75	3.04	0.108	0.12
е	0.85	1.05	0.033	0.041
e1	1.7	2.1	0.067	0.083
E	1.2	1.6	0.047	0.063
Н	2.1	2.75	0.083	0.108
L	0.6 typ.		0.024	4 typ.
S	0.35	0.65	0.014	0.026

Figure 9: Foot Print Dimensions (in millimeters)



**Table 7: Ordering Information** 

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BAR42FILM	D94				
BAR43FILM	D95				
BAR43AFILM	DB1	SOT23-3L	0.01 g	3000	Tape & reel
BAR43CFILM	DB2				
BAR43SFILM	DA5				

■ Epoxy meets UL94, V0

**Table 8: Revision History** 

Date	Revision	Description of Changes
Aug-2001	2B	Last update.
16-Apr-2005	3	Layout update. No content change.

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